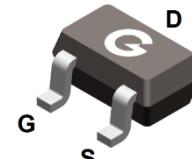
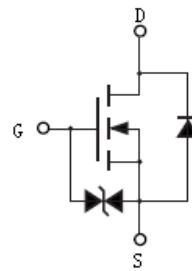


### Features

- Advanced trench cell design
- HBM: AEC-Q101-001: H1C (JESD22-A114-B: 1C)
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-323

### APPLICATIONS

- Load switch appliances

### Mechanical Data

- Case: SOT-323
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TBL3428W	SOT-323	3000 pcs / Tape & Reel	3428

### Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	30	V
Gate-to-Source Voltage	$V_{GSS}$	$\pm 10$	V
Continuous Drain Current <sup>*1</sup>	$I_D$	0.4	A
Continuous Drain Current ( $T_A = 70^\circ\text{C}$ ) <sup>*1</sup>		0.32	A
Pulsed Drain Current ( $t_p = 10\mu\text{s}$ )	$I_{DM}$	1.6	A
Power Dissipation <sup>*1</sup>	$P_D$	0.35	W
Operating Junction Temperature Range	$T_J$	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

### Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Air <sup>*1</sup>	$R_{\theta JA}$	-	325	357	$^\circ\text{C}/\text{W}$

### Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
$V_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	30	-	-	V
$I_{DS(0)}$	Zero Gate Voltage Drain Current	$V_{DS} = 24\text{V}, V_{GS} = 0\text{V}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS} = \pm 8\text{V}, V_{DS} = 0\text{V}$	-	-	$\pm 10$	$\mu\text{A}$
<b>On Characteristics</b>						
$R_{DS(ON)}$	Drain-Source On-resistance <sup>*2</sup>	$V_{GS} = 4.5\text{V}, I_D = 0.3\text{A}$	-	-	1.2	$\Omega$
		$V_{GS} = 2.5\text{V}, I_D = 0.2\text{A}$	-	-	1.6	$\Omega$
		$V_{GS} = 1.8\text{V}, I_D = 0.1\text{A}$	-	-	2	$\Omega$
		$V_{GS} = 1.5\text{V}, I_D = 0.05\text{A}$	-	-	3	$\Omega$
		$V_{GS} = 1.2\text{V}, I_D = 0.02\text{A}$	-	-	4	$\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.4	-	1.0	V
<b>Dynamic Characteristics</b>						
$C_{ISS}$	Input Capacitance	$V_{GS} = 0\text{V}$ $V_{DS} = 10\text{V}$ $f = 1.0\text{MHz}$	-	45	-	pF
$C_{OSS}$	Output Capacitance		-	14	-	
$C_{RSS}$	Reverse Transfer Capacitance		-	0.8	-	
<b>Switching Characteristics</b>						
$t_{d(ON)}$	Turn-on Delay Time <sup>*3</sup>	$V_{DD} = 10\text{V}$ $V_{GS} = 4\text{V}$ $R_G = 10\Omega$ $I_D = 0.3\text{A}$	-	8.3	-	ns
$t_r$	Turn-on Rise Time <sup>*3</sup>		-	5.7	-	
$t_{d(OFF)}$	Turn-Off Delay Time <sup>*3</sup>		-	35	-	
$t_f$	Turn-Off Fall Time <sup>*3</sup>		-	12	-	
$Q_G$	Total Gate-Charge	$V_{DD} = 10\text{V}$ $V_{GS} = 4.5\text{V}$ $I_D = 0.3\text{A}$	-	0.9	-	nC
$Q_{GS}$	Gate to Source Charge		-	0.3	-	
$Q_{GD}$	Gate to Drain (Miller) Charge		-	0.2	-	
<b>Source-Drain Diode Characteristics</b>						
$V_{SD}$	Diode Forward Voltage <sup>*2</sup>	$I_{SD} = 0.3\text{A}, V_{GS} = 0\text{V}$	-	-	1.3	V

Notes:

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper
2. The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$
3. Guaranteed by design, not subject to production



## Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

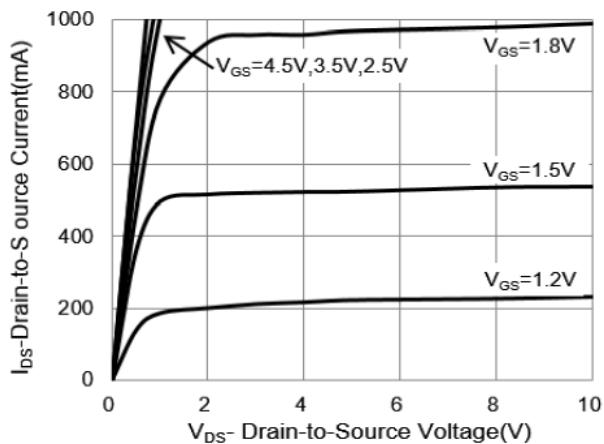


Fig 1 On-Region Characteristics

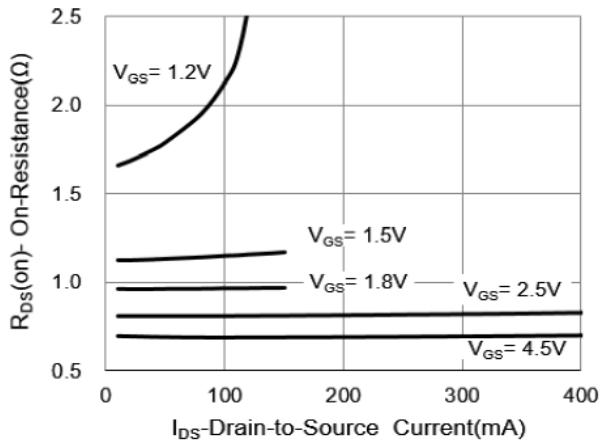


Fig 2 On-Resistance vs. Drain Current  
and Gate Voltage

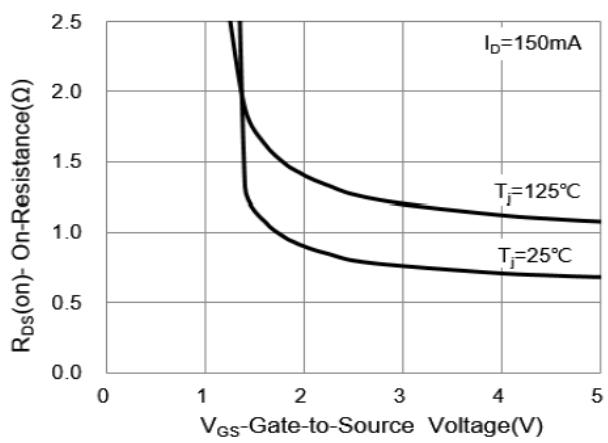


Fig 3 On-Resistance vs. Gate-Source Voltage

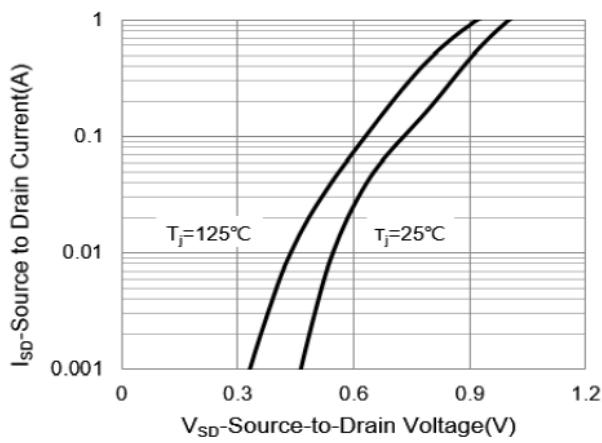


Fig 4 Body-Diode Characteristics

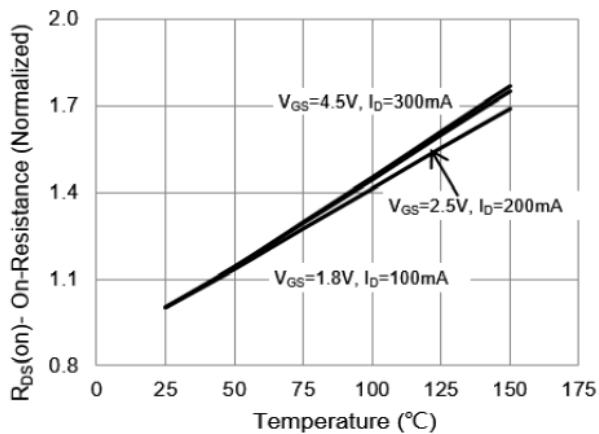


Fig 5 On-Resistance vs. Junction Temperature

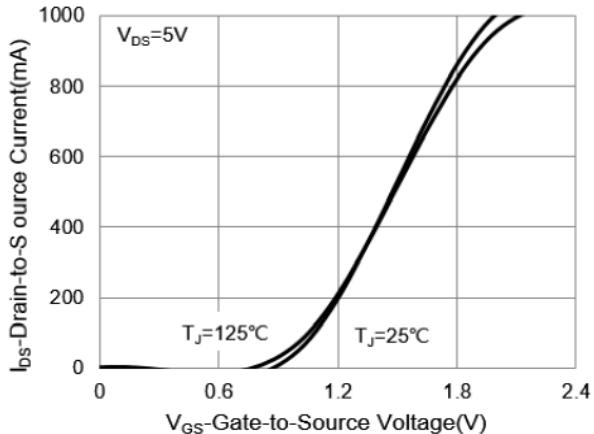


Fig 6 Transfer Characteristics

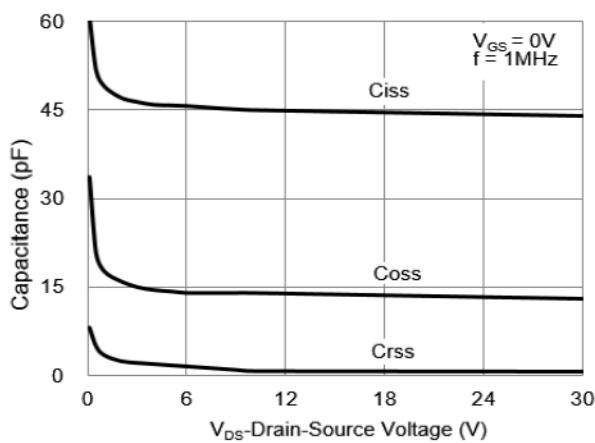


Fig 7 Capacitance Characteristics

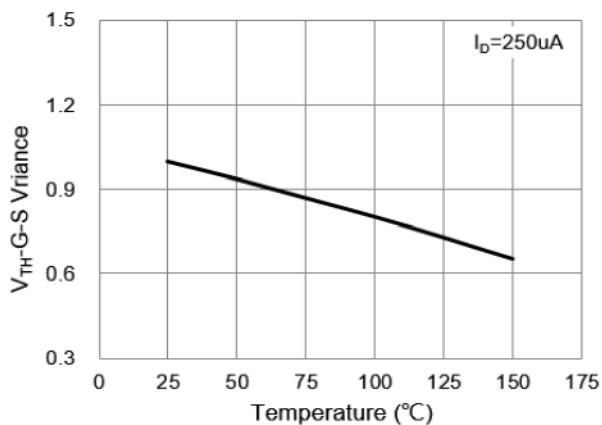


Fig 8 Gate Voltage vs. Junction Temperature

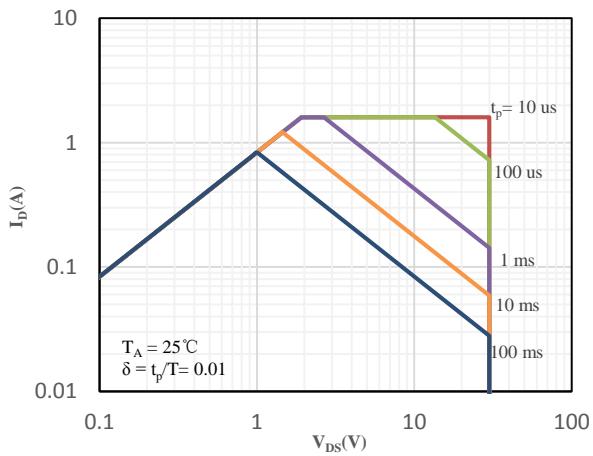


Fig 11 Safe Operation Area

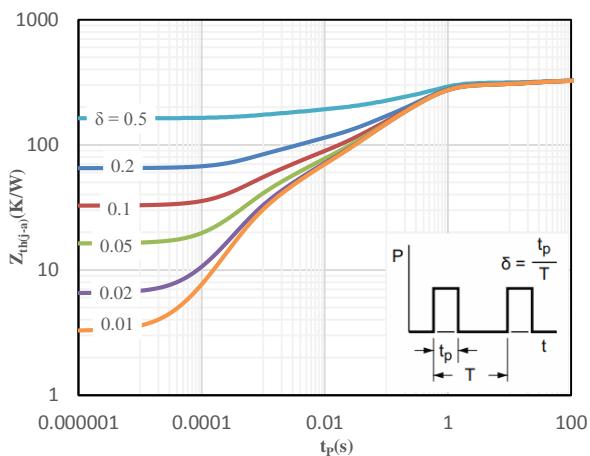
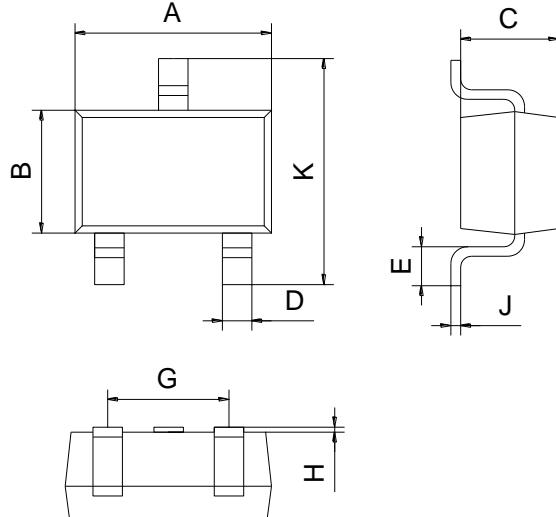


Fig 12 Maximum transient thermal impedance

**Package Outline Dimensions** (Unit: mm)



SOT-323		
Dimension	Min.	Max.
A	2.00	2.20
B	1.15	1.35
C	0.90	1.10
D	0.15	0.35
E	0.25	0.40
G	1.20	1.40
H	0.02	0.10
J	0.05	0.15
K	2.20	2.40

**Mounting Pad Layout** (Unit: mm)

